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CORRECTION



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Correction: Facile, wafer-scale compatible growth of ZnO nanowires *via* chemical bath deposition: assessment of zinc ion contribution and other limiting factors

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Correction for 'Facile, wafer-scale compatible growth of ZnO nanowires *via* chemical bath deposition: assessment of zinc ion contribution and other limiting factors' by Yu-Chen Huang *et al.*, *Nanoscale Adv.*, 2020, DOI: 10.1039/d0na00434k.

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